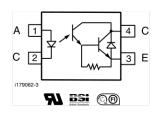


Vishay Semiconductors

Optocoupler, Photodarlington Output, High Gain, 300 V BV_{CEO}





FEATURES

- High collector emitter voltage, V_{CEO} = 300 V
- High isolation test voltage: 5300 V_{RMS}
- · Standard plastic DIP-4 package
- Compatible with Toshiba TLP627
- Compliant to RoHS Directive to 2002/95/EC and in accordance WEEE 2002/96/EC





RoHS

DESCRIPTION

The SFH619A is optically coupled isolators with a gallium arsenide infrared LED and a silicon photodarlington sensor. Switching can be achieved while maintaining a high degree of isolation between driving and load circuits. These optocouplers can be used to replace reed and mercury relays with advantages of long life, high speed switching and elimination of magnetic fields.

AGENCY APPROVALS

- UL file no. E52744 system code H
- BSI IEC 60950; IEC 60065
- FIMKO

ORDERING INFORMATION				
S F H 6 1 9 A - X PART NUMBER PAC	O O # T # CKAGE OPTION TAPE TAPE AND AND REEL REEL OPTION Option 7 Option 9 > 0.1 mm			
AGENCY CERTIFIED/PACKAGE	CTR (%)			
UL, BSI, FIMKO	≥ 1000			
DIP-4	SFH619A			
SMD-4, option 7	SFH619A-X007T (1)			
SMD-4, option 9 SFH619A-X009T ⁽¹⁾				
SMD-4, option 9 SFH619A-X009T0 ⁽²⁾				

Notes

- Additional options may be possible, please contact sales office.
- (1) Also available in tubes; do not put T on the end.
- (2) Option with 90° rotation.

ABSOLUTE MAXIMUM RATINGS (T _{amb} = 25 °C, unless otherwise specified)								
PARAMETER	TEST CONDITION	EST CONDITION SYMBOL VALUE UNI						
INPUT								
Peak reverse voltage		V _{RM}	6	V				
Forward continuous current		I _F	60	mA				
Derate linearly from 25 °C			1.33	mW/°C				
Power dissipation		P _{diss}	100	mW				
OUTPUT								
Collector emitter breakdown voltage		BV _{CEO}	300	V				
Emitter collector breakdown voltage		BV _{ECO}	0.3	V				
Collector (load) current		Ic	125	mA				
Derate linearly from 25 °C			2	mW/°C				
Power dissipation		P _{diss}	150	mW				



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ABSOLUTE MAXIMUM RATINGS (T _{amb} = 25 °C, unless otherwise specified)								
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT				
COUPLER	COUPLER							
Derate linearly from 25 °C			3.33	mW/°C				
Total power dissipation		P _{tot}	250	mW				
Isolation test voltage between emitter and detector	t = 1 s	V _{ISO}	5300	V _{RMS}				
Isolation resistance	V _{IO} = 500 V, T _{amb} = 25 °C	R _{IO}	≥ 10 ¹²	Ω				
Isolation resistance	V _{IO} = 500 V, T _{amb} = 100 °C	R _{IO}	≥ 10 ¹¹	Ω				
Storage temperature		T _{stg}	- 55 to + 150	°C				
Operating temperature		T _{amb}	- 55 to + 100	°C				
Soldering temperature (1)	max. 10 s, dip soldering: distance to seating plane ≥ 1.5 mm	T _{sld}	260	°C				

Notes

- Stresses in excess of the absolute maximum ratings can cause permanent damage to the device. Functional operation of the device is not
 implied at these or any other conditions in excess of those given in the operational sections of this document. Exposure to absolute
 maximum ratings for extended periods of the time can adversely affect reliability.
- (1) Refer to reflow profile for soldering conditions for surface mounted devices (SMD). Refer to wave profile for soldering conditions for through hole devices (DIP).

ELECTRICAL CHARACTERISTICS (T _{amb} = 25 °C, unless otherwise specified)								
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT		
INPUT	INPUT							
Forward voltage	I _F = 10 mA	V _F		1.2	1.5	V		
Reverse current	V _R = 6 V	I _R		0.02	10	μA		
Capacitance	V _R = 0 V	Co		14		pF		
OUTPUT		_						
Collector emitter breakdown voltage	I _{CE} = 100 μA	BV _{CEO}	300			V		
Emitter collector breakdown voltage	I _{EC} = 100 μA	BV _{ECO}	0.3			V		
Collector emitter dark current	V _{CE} = 200 V,T _A = 25 °C	I _{CEO}		10	200	nA		
Collector enlitter dark current	V _{CE} = 200 V,T _A = 100 °C	I _{CEO}			20	nA		
Collector emitter capacitance	$V_{CE} = 0 V, f = 1 MHz$	C _{CE}		39		pF		
COUPLER	COUPLER							
Collector emitter saturation voltage	$I_F = 1 \text{ mA}, I_C = 10 \text{ mA}$	V _{CEsat}			1	V		
	I _F = 10 mA, I _C = 100 mA	V _{CEsat}	0.3		1.2	V		
Coupling capacitance	$V_{I-O} = 0 V, f = 1 MHz$	C _C		0.6		pF		

Note

Minimum and maximum values are testing requirements. Typical values are characteristics of the device and are the result of engineering
evaluation. Typical values are for information only and are not part of the testing requirements.

CURRENT TRANSFER	RATIO					
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
Coupling transfer ratio	$I_F = 1 \text{ mA}, V_{CE} = 1 \text{ V}$	CTR	1000			%

SWITCHING CHARACTERISTICS						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
Rise time	V_{CC} = 10 V, I_{C} = 10 mA, R_{L} = 100 Ω	t _r		3.5		μs
hise time	$V_{CC} = 10 \text{ V}, I_F = 16 \text{ mA}, R_L = 180 \Omega$	t _r		1		μs
Fall time	$V_{CC} = 10 \text{ V}, I_{C} = 10 \text{ mA}, R_{L} = 100 \Omega$	t _f		14.5		μs
	$V_{CC} = 10 \text{ V}, I_F = 16 \text{ mA}, R_L = 180 \Omega$	t _f		20.5		μs
Turn-on time	$V_{CC} = 10 \text{ V}, I_{C} = 10 \text{ mA}, R_{L} = 100 \Omega$	t _{on}		4.5		μs
Turri-on time	$V_{CC} = 10 \text{ V}, I_F = 16 \text{ mA}, R_L = 180 \Omega$	t _{on}		1.5		μs
Turn-off time	V_{CC} = 10 V, I_{C} = 10 mA, R_{L} = 100 Ω	t _{off}		29		μs
Turn-on time	V_{CC} = 10 V, I_F = 16 mA, R_L = 180 Ω	t _{off}		53.5		μs

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SAFETY AND INSULATION RATINGS							
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT	
Climatic classification (according to IEC 68 part 1)				55/100/21			
Comparative tracking index		CTI	175		399		
V _{IOTM}			10000			V	
V _{IORM}			890			V	
P _{SO}					400	mW	
I _{SI}					275	mA	
T _{SI}					175	°C	
Creepage distance	standard DIP-4		7			mm	
Clearance distance	standard DIP-4		7			mm	
Creepage distance	400 mil DIP-4		8			mm	
Clearance distance	400 mil DIP-4		8			mm	
Insulation thickness, reinforced rated	per IEC 60950 2.10.5.1		0.4			mm	

Note

TYPICAL CHARACTERISTICS (T_{amb} = 25 °C, unless otherwise specified)

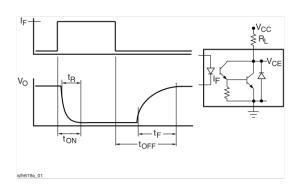


Fig. 1 - Switching Waveform and Switching Schematic

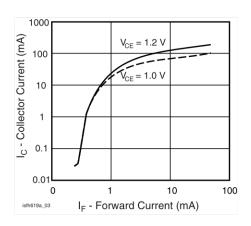


Fig. 2 - Collector Current (mA) vs. Forward Current (mA)

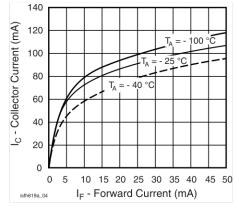


Fig. 3 - Collector Current vs. Forward Current

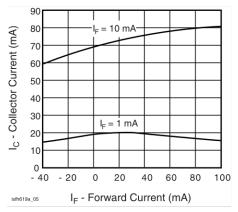


Fig. 4 - Collector Current vs. Ambient Temperature

[•] As per IEC 60747-5-2, § 7.4.3.8.1, this optocoupler is suitable for "safe electrical insulation" only within the safety ratings. Compliance with the safety ratings shall be ensured by means of protective circuits.



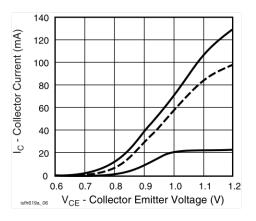


Fig. 5 - Collector Current vs. Collector Emitter Voltage

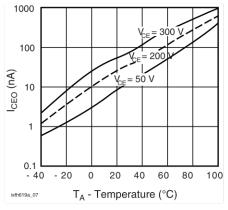


Fig. 6 - Collector Emitter Dark Current vs. Collector Emitter Voltage over Temperature

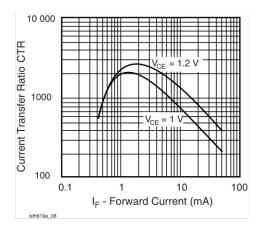


Fig. 7 - Current Transfer Ratio vs. Forward Current

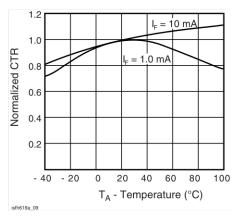


Fig. 8 - Normalized CTR vs. Temperature

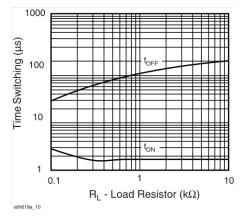
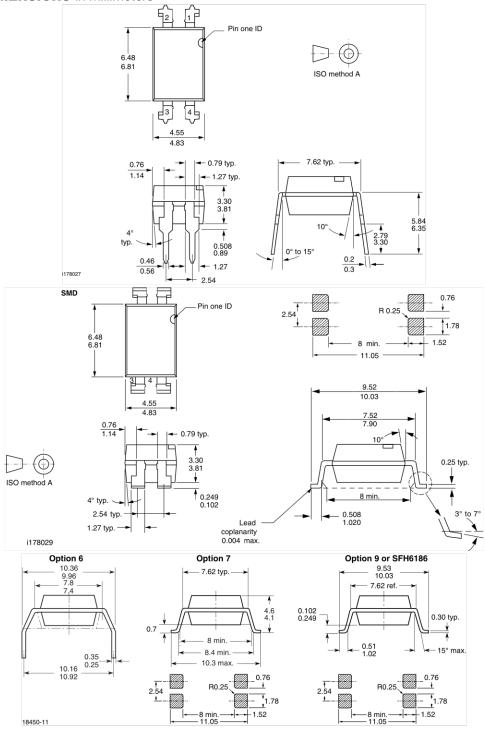


Fig. 9 - Switching Time vs. Load Resistor

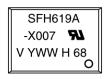




PACKAGE DIMENSIONS in millimeters



PACKAGE MARKING (example)



Notes

- Only option 7 reflected in the package marking.
- Tape and reel suffix (T) is not part of the package marking.



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